







LM53600-Q1, LM53601-Q1 SNAS660D - JUNE 2015 - REVISED MAY 2021

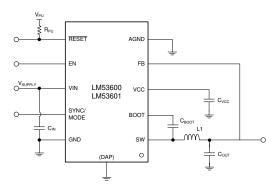
# LM53600/01-Q1 0.65-A/1-A, 36-V Synchronous, 2.1-MHz **Automotive Step-Down DC/DC Converter**

## 1 Features

- Qualified for automotive applications
- AEC-Q100 qualified with the following results:
  - Device temperature grade 1: –40°C to 125°C ambient operating temperature range
  - Device HBM classification level 2
  - Device CDM classification level C5
- -40°C to 150°C junction temperature range (available)
- Wide operating input voltage: 3.55 V to 36 V (with transient to 42 V)
- Spread spectrum option available
- 2.1-MHz fixed switching frequency
- Low quiescent current: 23 µA
- Shutdown current: 1.8 µA
- Adjustable, 3.3-V, or 5-V output
- Maximum current load: 650 mA for LM53600-Q1. 1000 mA for LM53601-Q1
- Pin-selectable forced PWM mode
- RESET output with filter and delay release
- External frequency synchronization
- Internal compensation, soft start, current limit, and **UVLO**
- 10-lead, 3-mm × 3-mm SON package with wettable and non-wettable flanks

## 2 Applications

- Automotive camera applications
- Automotive driver assistance systems
- Automotive body applications



Simplified Schematic - Fixed Output

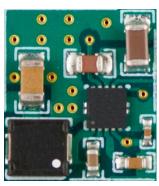
## 3 Description

The LM53600-Q1 and LM53601-Q1 synchronous buck regulator devices are optimized for automotive applications, providing an output voltage of 5 V, 3.3 V, or an adjustable output. Load current up to 650 mA is supported by the LM53600-Q1, while the LM53601-Q1 supports up to 1000 mA. Advanced high-speed circuitry allows the LM53600-Q1 and LM53601-Q1 devices to regulate from an input of 18 V to an output of 3.3 V at a fixed frequency of 2.1 MHz. Innovative architecture allows the device to regulate a 3.3-V output from an input voltage of only 3.8 V. The input voltage range up to 36 V, with transient tolerance of up to 42 V, eases input surge protection design. An open drain reset output, with filtering and delayed release, provides a true indication of system status. This feature negates the requirement for an additional supervisory component, saving cost and board space. Seamless transitions between PWM and PFM modes, along with a quiescent current of only 23 µA, ensures high efficiency and superior transient response at all loads. Few external components are needed allowing the generation of compact PCB layout. While the LM53600-Q1 and LM53601-Q1 devices are Q1 rated. electrical characteristics are ensured across a junction temperature range of -40°C up to 150°C.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	BODY SIZE (NOM)
LM53600-Q1	WSON (10)	3.00 mm x 3.00 mm
LM53601-Q1	WSON (10)	3.00 111111 X 3.00 111111

For all available packages, see the orderable addendum at the end of the data sheet.



Automotive 11.2-mm x 12.7-mm Layout



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Changed device status from product preview to production data......1

Changes from Revision \* (June 2015) to Revision A (December 2015)



## **5 Device Comparison**

## LM53600-Q1 Devices

Part Number <sup>(1)</sup>	Output Voltage	Spread Spectrum	Package Qty (2)	Wettable (WF)/Non-Wettable Flanks (non-WF)
LM53600AQDSXRQ1	Adjustable	No	3000	WF
LM53600AQDSXTQ1	Adjustable	No	250	WF
LM536003QDSXRQ1	3.3 V	No	3000	WF
LM536003QDSXTQ1	3.3 V	No	250	WF
LM536005QDSXRQ1	5.0 V	No	3000	WF
LM536005QDSXTQ1	5.0 V	No	250	WF
LM53600MQDSXRQ1	Adjustable	Yes	3000	WF
LM53600MQDSXTQ1	Adjustable	Yes	250	WF
LM53600NQDSXRQ1	3.3 V	Yes	3000	WF
LM53600NQDSXTQ1	3.3 V	Yes	250	WF
LM53600LQDSXRQ1	5.0 V	Yes	3000	WF
LM53600LQDSXTQ1	5.0 V	Yes	250	WF
LM53600MQUDSXRQ1	Adjustable	Yes	3000	Non-WF

- (1) LM53600-Q1 devices have maximum recommended operating current of 650 mA.
- (2) See Package Option Addendum for tape and reel details as well as links used to order parts.

### LM53601-Q1 Devices

Part Number <sup>(1)</sup>	Output Voltage	Spread Spectrum	Package Qty (2)	Wettable (WF)/Non-Wettable Flanks (non-WF)
LM53601AQDSXRQ1	Adjustable	No	3000	WF
LM53601AQDSXTQ1	Adjustable	No	250	WF
LM536013QDSXRQ1	3.3 V	No	3000	WF
LM536013QDSXTQ1	3.3 V	No	250	WF
LM536015QDSXRQ1	5.0 V	No	3000	WF
LM536015QDSXTQ1	5.0 V	No	250	WF
LM53601MQDSXRQ1	Adjustable	Yes	3000	WF
LM53601MQDSXTQ1	Adjustable	Yes	250	WF
LM53601NQDSXRQ1	3.3 V	Yes	3000	WF
LM53601NQDSXTQ1	3.3 V	Yes	250	WF
LM53601LQDSXRQ1	5.0 V	Yes	3000	WF
LM53601LQDSXTQ1	5.0 V	Yes	250	WF
LM536015QUDSXRQ1	5.0 V	No	3000	Non-WF
LM536013QUDSXRQ1	3.3 V	No	3000	Non-WF
LM53601MQUDSXRQ1	Adjustable	Yes	3000	Non-WF

- (1) LM53601-Q1 devices have maximum recommended operating current of 1000 mA.
- (2) See Package Option Addendum for tape and reel details as well as links used to order parts.



## **6 Pin Configuration and Functions**

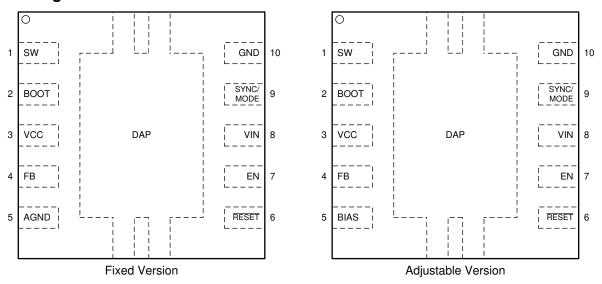


Figure 6-1. DSX Package 10-Pin WSON Top View

**Table 6-1. Pin Functions** 

	PIN	TYPE(1)	DESCRIPTION				
NO.	NAME	ITPE	DESCRIPTION				
1	SW	Р	Regulator switch node. Connect to output inductor.				
2	воот	I	High side gate driver upper supply rail. Connect a 100-nF capacitor from SW pin to BOOT. An internal diode charges the capacitor while SW node is low.				
3	VCC	Р	Internal 3-V regulator output. Used as supply to internal control circuits. Connect a high quality 1.0-capacitor from this pin to AGND for fixed versions or to GND for adjustable versions.				
4	FB (Fixed Versions)	I/P	Fixed version only, this pin serves as feedback for output voltage as well as power source for VCC's regulator. Connect to output node. Place 10-nF bypass capacitor immediately adjacent to this pin.				
4	FB (ADJ Version)	I	ADJ version only, this pin serves as feedback for output voltage only. Connect to output through a voltage divider which determines output voltage set point.				
5	AGND (Fixed Version)	G	ixed versions only, this is the ground to which input signals and FB are compared.				
3	BIAS (ADJ Version)	Р	Power source for VCC's regulator. Connect to output node. Place 10-nF bypass capacitor immediately adjacent to this pin.				
6	RESET	0	Open drain reset output. Connect to suitable voltage supply through a current limiting pull up resistor. High = regulator OK, Low = regulator fault. Will go low when EN = low. See Detailed Description.				
7	EN	I	Enable input to regulator. High = on, Low = off. Can be connected to Vin. Do not float.				
8	VIN	I	Input supply to regulator. Connect input bypass capacitors directly between this pin and GND.				
9	SYNC/MODE	I	This is a multifunction mode control input which is tolerant of voltages up to input voltage. With a valid synchronization signal at this pin, the device will switch in forced PWM mode at the external clock frequency and synchronize with it at the rising edge of the clock. See the <i>Electrical Characteristics</i> for synchronization signal specifications. With this input tied high, the device will switch at the internal clock frequency in forced PWM mode. With this input tied low, the device will switch at the internal clock frequency in AUTO mode with diode emulation at light load. Spread spectrum is disabled if there is a valid synchronization signal. Do not float.				
10	GND	G	Bypass to VIN immediately adjacent to this pin.				
DAP (EXPO SED PAD)	Thermal, GND	Thermal	Connect to ground – The sole function of the DAP interface is the thermal improvement of the device, a direct thermal connection to a ground plane is required. The DAP is not meant as an electrical interconnect. Electrical characteristics are not ensured.				

(1) G = Ground, I = Input, O = Output, P = Power



## 7 Specifications

## 7.1 Absolute Maximum Ratings

Over the recommended operating junction temperature range of -40°C to 150°C (unless otherwise noted)

	MIN	MAX	UNIT
VIN to GND <sup>(1)</sup>	-0.3	42	
SW to GND <sup>(2)</sup>	-0.3	VIN+0.3	
BOOT to SW	-0.3	3.6	
EN to GND (1)	-0.3	42	V
BIAS to GND: LM53600-Q1/LM53601-Q1-ADJ	-0.3	16	V
FB to GND : LM53600-Q1/LM53601-Q1 - 3.3 V, LM53600-Q1/LM53601-Q1 - 5.0 V	-0.3	16	
FB to GND : LM53600-Q1/LM53601-Q1-ADJ	-0.3	5.5	
RESET to GND	-0.3	8	
RESET sink current <sup>(3)</sup>		8	mA
SYNC/MODE to GND <sup>(1)</sup>	-0.3	42	
VCC	-0.3	3.6	V
GND <sup>(4)</sup> to AGND (Fixed version only)	-1	2	
Storage temperature, T <sub>stg</sub>	-40	150	°C

- (1) A maximum of 42 V can be sustained at this pin for a duration of ≤100 ms at a duty cycle of ≤1%.
- (2) A voltage of 2-V below GND and 2-V above VIN can appear on this pin for ≤200 ns with a duty cycle of ≤ 0.01%.
- Do not exceed pin's voltage rating.
- (4) This specification applies to voltage durations of 1 µs or less. The maximum D.C. voltage should not exceed ±0.3 V.

## 7.2 ESD Ratings

				VALUE	UNIT
V <sub>(ESD)</sub> Electrostatic discharge		VIN, SW, CBOOT	±2000		
	Human body model (HBM), per AEC Q100-002 <sup>(1)</sup>	EN, BIAS, RESET, FB, SYNC, PWM, VCC	±2000	V	
	,	Charged device model (CDM), per AEC Q100-011	Other pins	±750	
		Charged device model (CDIVI), per ALC Q100-011	Corner pins (1, 5, 6, and 10)	±750	

(1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification

### 7.3 Recommended Operating Conditions

Over the recommended operating junction temperature range of -40°C to 150°C (unless otherwise noted)

		MIN	NOM MAX	UNIT
Input voltage range after startup <sup>(1)</sup>		3.8	36	V
Output voltage range	5 V <sup>(2)</sup>	0	5.5	V
Output voitage range	3.3 V <sup>(2)</sup>	0	3.63	V
Output adjustment range <sup>(3)</sup> for LM53600-Q1	-ADJ <sup>(2)</sup> , LM53601-Q1-ADJ <sup>(2)</sup>	3.3	6	V
Load ourrent range	LM53600-Q1	0	650	mA
Load current range	LM53601-Q1	0	1000	ША
Operating junction temperature <sup>(4)</sup>		-40	150	°C

- (1) An extended input voltage range to 3.55 V is possible; see Section 7.6. See input UVLO in Section 7.5 for startup conditions.
- (2) Output voltage should not be allowed to fall below 0 V during normal operation.
- 3) The LM53600-Q1 and LM53601-Q1 devices can operate outside of the listed range output voltage range. For output voltage outside of the listed range, contact Texas Instruments concerning alternate application circuit BOM and additional operational limitations such as higher I<sub>O</sub>.
- (4) High junction temperatures degrade operating lifetimes. Operating lifetime is de-rated for junction temperatures greater than 125°C.



### 7.4 Thermal Information

		LM53600-Q1, LM53601-Q1		
	THERMAL METRIC <sup>(1)</sup>	DSX (WSON)	UNIT	
R <sub>0 JA</sub>	Junction -to-ambient thermal resistance	46.2	°C/W	
R <sub>θ JC</sub>	Junction -to-case (top) thermal resistance	31.5	°C/W	
R <sub>0 JB</sub>	Junction -to-board thermal resistance	20.9	°C/W	
ФЈТ	Junction- to-top characterization parameter	0.3	°C/W	
ФЈВ	Junction-to-board characterization parameter	21.0	°C/W	
R <sub>θ JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	4.1	°C/W	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report (SPRA953).

## 7.5 Electrical Characteristics

Limits apply to the recommended operating junction temperature range of  $-40^{\circ}$ C to  $150^{\circ}$ C, unless otherwise noted. Minimum and maximum limits are ensured through test, design or statistical correlation. Typical values represent the most likely parametric norm at  $T_j = 25^{\circ}$ C, and are provided for reference purposes only. Unless otherwise stated the following conditions apply:  $V_{in} = 13.5 \text{ V}$ .

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>FB</sub>	Initial output voltage accuracy	V <sub>in</sub> = 3.8 V to 36 V T <sub>j</sub> =25°C, Open Loop	-1%		1%	
		V <sub>in</sub> = 3.8 V to 36 V, Open Loop	-1.5%		1.5%	
IQ	Operating quiescent current;	V <sub>in</sub> = 13.5 V, Not switching V <sub>bias</sub> = 5 V		6.5		
	measured at V <sub>IN</sub> pin	V <sub>in</sub> = 13.5 V, Not switching V <sub>bias</sub> = 5 V, T <sub>j</sub> = 85°C			16	μA
I <sub>B</sub>	Bias current into BIAS pin for adjustable versions and FB pin for fixed versions	V <sub>in</sub> = 13.5 V, Not switching V <sub>bias</sub> = 5 V, Mode = 0 V		46	80	μ
I <sub>SD</sub>	Shutdown quiescent current;	EN = 0, VIN = 13.5 V T <sub>j</sub> = 25°C		1.8		
	measured at V <sub>IN</sub> pin	EN = 0, VIN = 13.5 V T <sub>j</sub> = 85°C			3	μΑ
V <sub>in_UVLO</sub>	Minimum input voltage to operate	Rising	3.2	3.6	3.75	V
V <sub>in_UVLO _hyst</sub>	Minimum input voltage hysteresis	Hysteresis	0.2	0.3	0.35	V
V <sub>reset_OV</sub>	RESET upper threshold voltage	Rising, % of Vout	105%	106.5%	110%	
V <sub>reset_UV</sub>	RESET lower threshold voltage	Falling, % Vout	92%	94%	97%	
V <sub>reset_guard</sub>	Magnitude of RESET lower threshold difference from steady state output voltage	Steady state output voltage and RESET threshold read at the same T <sub>J</sub> , and V <sub>IN</sub>	3.9%			
V <sub>reset_hyst</sub>	RESET hysteresis as a percent of output voltage set point			1%		
V <sub>reset_valid</sub>	Minimum input voltage for proper RESET function	50 μA pull-up to $\overline{RESET}$ pin, $EN = 0$ V, $T_j = 25$ °C			1.5	V
		50 $\mu$ A pull-up to RESET pin, Vin = 1.5 V, EN = 0 V, $T_j$ = 25°C			0.4	
V <sub>OL</sub>	Low level RESET function output voltage	0.5mA pull-up to RESET pin, Vin = 13.5 V, EN = 0 V			0.4	V
		1mA pull-up to RESET pin, Vin = 13.5 V, EN = 3.3 V			0.4	



Limits apply to the recommended operating junction temperature range of -40°C to 150°C, unless otherwise noted. Minimum and maximum limits are ensured through test, design or statistical correlation. Typical values represent the most likely

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		V <sub>IN</sub> = 13.5 V, Center frequency with spread spectrum, PWM operation	1.89	2.1	2.4	
=	Outlieble of the many	V <sub>IN</sub> = 13.5 V, Without spread spectrum, PWM operation	1.89	2.1	2.4	M⊔→
= sw	Switching frequency	V <sub>IN</sub> = 36 V, 3.3-V fixed output device and adjustable devices regardless of output voltage		1.0		MHz
		V <sub>IN</sub> = 36 V, 5-V fixed output device		1.5		
SYNC	Sync frequency range	Output setting + 1 V < V <sub>IN</sub> < 18 V	1.9	2.1	2.3	MHz
D <sub>SYNC</sub>	Sync input duty cycle range	High state input < 5.5 V and > 2.3 V	25%		75%	
	SYNC/MODE input threshold voltage	SYNC/MODE input high (MODE=FPWM)	1.5			
SYNC/MODE		SYNC/MODE input low (MODE = AUTO with diode emulation)			0.4	V
		SYNC/MODE input hysteresis	0.185		1	
F <sub>SSS</sub>	Frequency span of spread spectrum operation <sup>(2)</sup>			±4%		
F <sub>PSS</sub>	Spread spectrum pattern frequency <sup>(2)</sup>				30	Hz
I <sub>SYNC/MODE</sub>	SYNC/MODE leakage current	Vin = 13.5 V, V <sub>SYNC/MODE</sub> = 3.3 V		1		μA
		V <sub>IN</sub> = V <sub>SYNC/MODE</sub> = 13.5 V		5		μΛ
t <sub>MODE</sub>	Mode change transition time	To FPWM Mode 20 mA load, V <sub>IN</sub> = 13.5 V		100		μs
		To AUTO Mode 20-mA load, V <sub>IN</sub> = 13.5 V		60		
	High side switch current limit	LM53600-Q1 Duty cycle approaches 0%	1.0	1.35	1.65	^
L_HS	(1)	LM53601-Q1 Duty cycle approaches 0%	1.5	1.83	2.1	Α
1	Low aids switch surrent limit	LM53600-Q1	0.65	0.78	0.93	^
L_LS	Low side switch current limit	LM53601-Q1	1.0	1.2	1.43	Α
L_ZC	Zero-cross current limit MODE/SYNC = Low			-0.01		Α
	Negative current limit MODE/	LM53600-Q1		-0.7		^
L_NEG	SYNC = High	LM53601-Q1		-0.7		Α
D	Dawar switch on registance	High side MOSFET Rdson		220		mΩ
R <sub>dson</sub>	Power switch on-resistance	Low side MOSFET Rdson		200		
V <sub>EN</sub>	Enable input threshold voltage - rising	Enable rising	1.7	-	2.0	V
V <sub>EN_HYST</sub>	Enable threshold hysteresis		0.40	-	0.55	V
V <sub>EN_WAKE</sub>	Enable Wake-up threshold		0.4			V
EN	Enable pin input current	V <sub>IN</sub> = V <sub>EN</sub> = 13.5 V		2.7		μΑ
.,	Internal Veg veltage	V <sub>IN</sub> = 13.5 V, V <sub>bias</sub> = 0 V		3.05		V
V <sub>cc</sub>	Internal Vcc voltage	V <sub>IN</sub> = 13.5 V, V <sub>bias</sub> = 3.3 V		3.15		V
V <sub>cc_UVLO</sub>	Internal Vcc input under voltage lock-out	VCC rising		2.7		V
V <sub>cc_UVLO_hyst</sub>	Input under voltage lock-out hysteresis	Hysteresis below V <sub>cc_uvlo</sub>		190		mV



Limits apply to the recommended operating junction temperature range of  $-40^{\circ}$ C to  $150^{\circ}$ C, unless otherwise noted. Minimum and maximum limits are ensured through test, design or statistical correlation. Typical values represent the most likely parametric norm at  $T_j = 25^{\circ}$ C, and are provided for reference purposes only. Unless otherwise stated the following conditions apply:  $V_{in} = 13.5 \text{ V}$ .

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I <sub>FB</sub>	Input current from FB to AGND	LM53600-Q1-ADJ, FB = 1 V		20		nA
V -	Reference voltage for ADJ	$T_j = 25^{\circ}C$	0.993	1	1.007	V
$V_{ref}$	option only		0.985	1	1.015	V
R <sub>RESET</sub>	Rdson of RESET output			50	120	Ω
T <sub>SD</sub>	Thermal shutdown rising threshold <sup>(2)</sup>		151	167	185	
T <sub>SDF</sub>	Thermal shutdown falling threshold <sup>(2)</sup>		140	157		°C
T <sub>SD_hyst</sub>	Thermal shutdown hysteresis <sup>(2)</sup>			10		
D	Maximum awitah dutu ayala(2)	Fsw = 2.1 MHz		76%		
D <sub>max</sub>	Maximum switch duty cycle <sup>(2)</sup>	While in frequency fold back	96%			

- (1) High side current limit is a function of duty factor. Current limit value is highest at small duty factor and less at higher duty factors.
- (2) Ensured by design, statistical analysis and production testing of correlated parameters; not tested in production.

## 7.6 System Characteristics

The following specifications are ensured by design provided that the component values in the typical application circuit are used. These parameters are not ensured by production testing. Limits apply to the recommended operating junction temperature range of  $-40^{\circ}$ C to  $150^{\circ}$ C, unless otherwise noted. Minimum and Maximum limits are ensured through test, design or statistical correlation. Typical values represent the most likely parametric norm at Tj =  $25^{\circ}$ C, and are provided for reference purposes only. Unless otherwise stated the following conditions apply: Vin = 13.5 V.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V <sub>in_min</sub>	Minimum input voltage for full functionality at 500-mA load, after start-up	V <sub>OUT</sub> = 3.3 V			3.55	V	
	Minimum input voltage for full functionality at 100% of max rated load, after start-up	V <sub>OUT</sub> = 3.3 V			3.8	V	
V	Output valtage for 2.2 V ention	V <sub>IN</sub> = 4.0 V to 36 V, I <sub>OUT</sub> = Maximum recommended load current	3.23	3.3	3.37		
V <sub>out_3_3V</sub>	Output voltage for 3.3-V option	V <sub>IN</sub> = 3.8 V to 36 V, I <sub>OUT</sub> =100 μA to 100 mA, typical value in Auto Mode	3.23	3.33	3.39	V	
V	Output voltage for F. V. ention	V <sub>IN</sub> = 5.8 V to 36 V, I <sub>OUT</sub> = Maximum recommended load current	4.9	4.9 5		V	
V <sub>out_5V</sub>	Output voltage for 5-V option	V <sub>IN</sub> = 5.5 V to 36 V, I <sub>OUT</sub> =100 μA to 100 mA, typical value in Auto Mode	4.9	5.05	5.125	V	
V	Output voltage ADJ option	V <sub>IN</sub> = V <sub>OUT</sub> + 0.6 V to 36 V, I <sub>OUT</sub> = 100 mA, FPWM mode	-2%		+2%		
V <sub>out_ADJ</sub>	Output voitage AD3 option	V <sub>IN</sub> = V <sub>OUT</sub> + 0.6 V to 36 V, I <sub>OUT</sub> =100 μA to 100 mA, Auto mode	-2%		+2.5%		
	Load regulation for ADJ option <sup>(1)</sup>	V <sub>IN</sub> = V <sub>OUT</sub> + 1 V to 36 V, I <sub>OUT</sub> = 0 A to 1 A, T <sub>J</sub> = 125°C, FPWM mode		-1%			
I <sub>Q_VIN</sub> (2)	Input current to V <sub>IN</sub> node of DC/DC utilizing the LM53600-Q1/LM53601-	V <sub>IN</sub> = 13.5 V, V <sub>OUT</sub> = 3.3 V, I <sub>OUT</sub> = 0 A	23			μA	
	Q1	V <sub>IN</sub> = 13.5 V, V <sub>OUT</sub> = 5 V, I <sub>OUT</sub> = 0 A		30			
V <sub>DROP1</sub>	Minimum input to output voltage differential to maintain regulation accuracy, without inductor DCR drop	V <sub>OUT</sub> =3.3 V, I <sub>OUT</sub> =1000 mA, +2/–3% output accuracy			0.6	V	



The following specifications are ensured by design provided that the component values in the typical application circuit are used. These parameters are not ensured by production testing. Limits apply to the recommended operating junction temperature range of  $-40^{\circ}$ C to  $150^{\circ}$ C, unless otherwise noted. Minimum and Maximum limits are ensured through test, design or statistical correlation. Typical values represent the most likely parametric norm at Tj =  $25^{\circ}$ C, and are provided for reference purposes only. Unless otherwise stated the following conditions apply: Vin = 13.5 V.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>DROP2</sub>	Minimum input to output voltage differential to maintain F <sub>SW</sub> ≥ 1.85 MHz, without inductor DCR drop	V <sub>OUT</sub> = 3.3 V, I <sub>OUT</sub> =1000 mA, F <sub>SW</sub> = 1.85 MHz, 2% regulation accuracy			2.0	V
Typical Efficiency without inductor	V <sub>IN</sub> = 13.5 V, V <sub>OUT</sub> = 5.0 V, I <sub>OUT</sub> = 1 A		85%			
	Typical Efficiency without inductor	V <sub>IN</sub> = 13.5 V, V <sub>OUT</sub> = 3.3 V, I <sub>OUT</sub> = 1 A	80%			
Efficiency	loss	V <sub>IN</sub> = 13.5 V, V <sub>OUT</sub> = 5.0 V, I <sub>OUT</sub> = 0.65 A		86%		
		V <sub>IN</sub> = 13.5 V, V <sub>OUT</sub> = 3.3 V, I <sub>OUT</sub> = 0.65 A		83%		

- (1) 125°C is worst case temperature for load regulation. Layout is critical since adjustable option does not have an AGND terminal.
- (2) See Section 8.3.7 in Section 8 for the meaning of this specification and how it can be calculated.

## 7.7 Timing Requirements

Limits apply to the recommended operating junction temperature range of  $-40^{\circ}$ C to  $150^{\circ}$ C, unless otherwise noted. Minimum and Maximum limits are ensured through test, design or statistical correlation. Typical values represent the most likely parametric norm at  $T_j = 25^{\circ}$ C, and are provided for reference purposes only. Unless otherwise stated the following conditions apply:  $V_{in} = 13.5 \text{ V}$ .

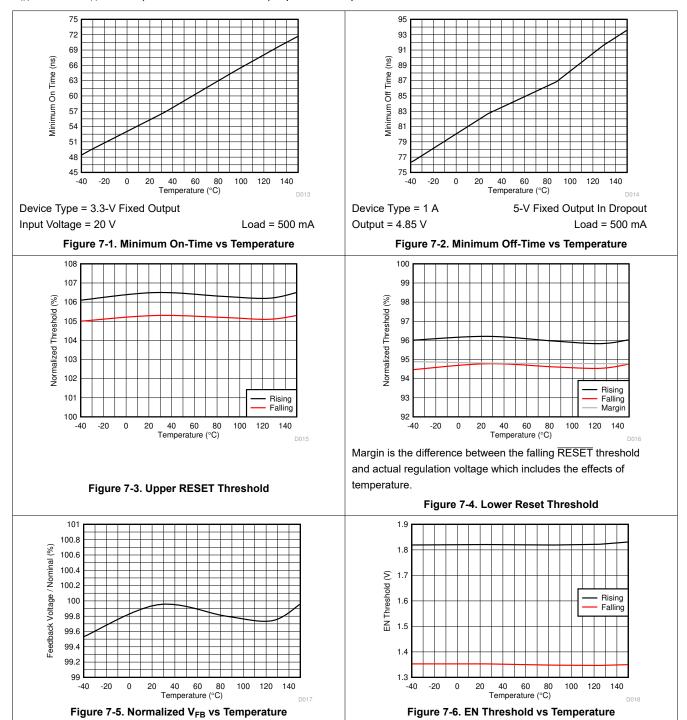
			MIN	NOM	MAX	UNIT
t <sub>on</sub>	Minimum switch on time <sup>(1)</sup>	V <sub>IN</sub> = 18 V, I <sub>OUT</sub> = 500 mA		50	80.5	20
t <sub>off</sub>	Minimum switch off time <sup>(1)</sup>	I <sub>OUT</sub> = 500 mA		90	125	ns
t <sub>reset_act</sub>	Delay time to RESET high signal		4	6	8	ms
t <sub>reset_filter</sub>	Glitch filter time constant for RESET function			24		μs
t <sub>SS</sub>	Soft-start time	Time from first SW node pulse to Vref at 90%, V <sub>IN</sub> ≥4.2 V	1.3	3	4.5	ms
t <sub>EN</sub>	Turn-on delay <sup>(2)</sup>	Time from EN high until first SW node pulse. $V_{IN}$ = 13.5, $Cvcc$ = 1 $\mu F$		0.7		ms
t <sub>W</sub>	Short circuit wait time ( <i>Hiccup</i> time)			4.5		ms

- (1) See Section 8
- (2) Ensured by design, statistical analysis and production testing of correlated parameters; not tested in production.



## 7.8 Typical Characteristics

 $V_{IN}$  = 13.5 V,  $T_A$  = 25°C (unless otherwise noted). Specified temperatures are ambient.





## 8 Detailed Description

### 8.1 Overview

The LM53600-Q1 and LM53601-Q1 devices are wide-input voltage range, low quiescent current, high-performance regulators with internal compensation designed specifically for the automotive market. These devices are designed to minimize end product cost and size while operating in demanding automotive environments. Normal operating frequency is 2.1 MHz allowing the use of small passive components. State of the art current limit allows the use of inductors that are smaller than those typically used in a 650mA or 1000mA regulator. 2.1MHz is above the AM band, allowing significant saving in input filtering. This part has a low unloaded current consumption eliminating the need for an external back-up LDO. The low shutdown current and high maximum operating voltage of the LM53600-Q1 and LM53601-Q1 devices also allows the elimination of an external load switch. To further reduce system cost, an advanced reset output is provided, which can often eliminate the use of an external reset or supervisory device.

The LM53600-Q1 and LM53601-Q1 devices are AEC Q1 qualified, and also have electrical characteristics ensured up to a maximum junction temperature of 150°C.

## 8.2 Functional Block Diagram

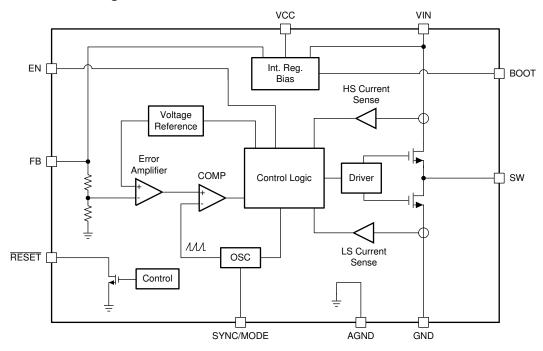


Figure 8-1. Fixed Versions



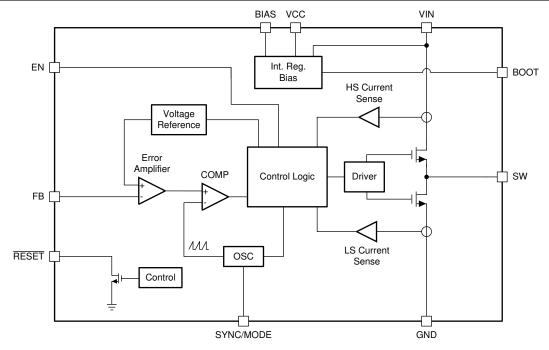


Figure 8-2. Adjustable Versions

## 8.3 Feature Description

#### 8.3.1 Control Scheme

The control scheme of the LM53600-Q1 and LM53601-Q1 devices allows this part to operate under a wide range of conditions with a low number of external components. Peak current mode control allows a wide range of input voltages and output capacitance values, while maintaining a constant switching frequency. Stable operation is maintained while output capacitance is changed during operation as well. This allows use in systems that require high performance during load transients and which have load switches which remove loads as system operating state changes. Short minimum on- and off-times ensure constant frequency regulation over a wide range of conversion ratios. These on- and off- times allow for a duty factor window of 13% to 77% at 2.1-MHz switching frequency.

This architecture uses frequency foldback in order to achieve low dropout voltage maintaining output regulation as the input voltage falls close to output voltage. The frequency foldback is smooth and continuous, and activated as off-time approaches its minimum. Under these conditions, the LM53600-Q1 and LM53601-Q1 devices operate much like a constant off-time converter allowing maximum duty cycle to reach 97%, which allows output voltage regulation with 600-mV dropout.

If input voltage exceeds approximately 21 V, frequency is reduced smoothly as a function of input voltage. This frequency reduction allows output voltage regulation and current mode control to operate with duty factor below 13%. Since current mode control continues at high input voltage insensitivity to output capacitance is maintained. This form of fold back will not be active if input voltage is below 18 V, insuring constant frequency operation over normal automotive operating conditions.

High input voltage foldback has two settings; see  $F_{SW}$  under 36-V input conditions for detail. Since adjustable output voltage versions fold back under high input voltage conditions as though output voltage were 3.3 V, larger inductance and output capacitance is required if an adjustable device is used with output voltage above 4.2 V. If a 4.7- $\mu$ H inductor is used in system with greater 4.2-V output using an adjustable device, the converter remains stable but may not achieve full output current when operating at high input voltages, such as 36 V, due to excessive inductor current ripple.

As load current is reduced, the LM53600-Q1 and LM53601-Q1 devices transition to light load mode if SYNC/MODE is low. In this mode, diode emulation is used to reduce RMS inductor current and switching frequency is reduced. Also, fixed voltage versions do not need a voltage divider connected to FB saving additional power. As

a result, only 23  $\mu$ A (typical, while converting 13.5 V to 3.3 V) is consumed to regulate output voltage if output is unloaded. Average output voltage increases slightly while lightly loaded.

#### 8.3.2 Soft-Start Function

Soft-start time is fixed internally at about 3.0 ms. Soft-start is achieved by ramping the internal reference. The LM53600-Q1 and LM53601-Q1 devices operate correctly even if there is a voltage present on output before activation of the LM53600-Q1 or LM53601-Q1.

#### 8.3.3 Current Limit

The LM53600-Q1 and LM53601-Q1 devices use two current limits which allow the use of smaller inductors than systems utilizing a single current limit. A coarse high side or peak current limit is provided to protect against faults and saturated inductors. High side current limit limits the duration of high sides FET's on period during a given clock cycle. A precision valley current limit prevents excessive average output current from the Buck converter of the LM53600-Q1 and LM53601-Q1 devices. A new switching cycle is not initiated until inductor current drops below the valley current limit. This scheme allows use of inductors with saturation current rated less than twice the rated operating current of the LM53600-Q1 or LM53601-Q1.

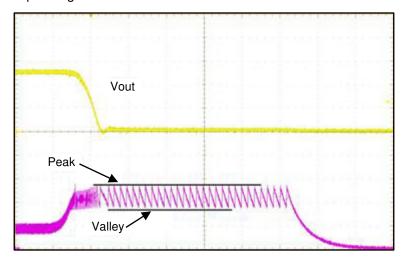


Figure 8-3. Current Limit Operation

Figure 8-3 shows the response of the LM53600-Q1 or LM53601-Q1 device to a short circuit: Peak current limit prevents excessive peak current while valley current limit prevents excessive average inductor current. After a small number of cycles, hiccup mode is activated.

### 8.3.4 Hiccup Mode

In order to prevent excessive heating and power consumption under sustained short circuit conditions, a hiccup mode is included. If an over current condition is maintained, the LM53600-Q1 or LM53601-Q1 device shuts off its output and waits for  $t_W$  (approximately 4.5 ms), after which the LM53600-Q1 or LM53601-Q1 restarts operation beginning by activating soft start.



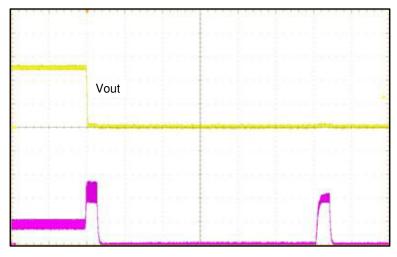


Figure 8-4. Hiccup Operation

Figure 8-4 shows hiccup mode operation: The switch node of the LM53600-Q1 LM53601-Q1 is high impedance after a short circuit or over current persists for a short duration. Periodically, the LM53600-Q1 or LM53601-Q1 attempts to restart. If the short has been removed before one of these restart attempts, the LM53600-Q1 or LM53601-Q1 operates normally.

### 8.3.5 RESET Function

While the reset function of the LM53600-Q1 and LM53601-Q1 devices resembles a standard power good function, its functionality is designed to replace a discrete reset IC, reducing BOM cost. There are three major differences between the reset function and the normal power good function seen in most regulators:

- · A delay has been added for release of reset. See waveforms below.
- RESET output signals a fault (pulls its output to ground) while the part is disabled.
- RESET continues to operate with input voltage as low as 1.5 V. Below this input voltage, RESET output may be high impedance.

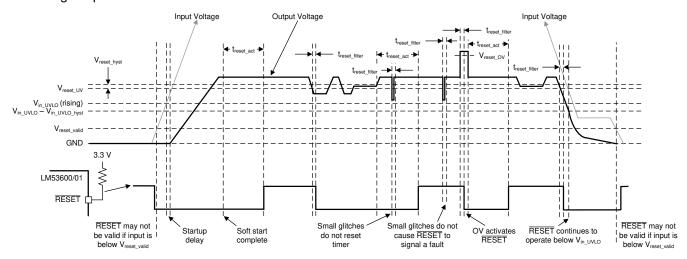


Figure 8-5. Reset Output Function Operation

The following table summarizes conditions that cause a fault to be flagged by  $\overline{\text{RESET}}$ . Once a fault is flagged,  $\overline{\text{RESET}}$  will not be released (become high impedance) until either there is no fault for  $t_{\text{reset\_act}}$  or VIN drops below  $V_{\text{reset}}$  valid.

Table showing conditions that cause RESET to signal a fault (pull low).

FAULT CONDITION INITIATED	FAULT CONDITION ENDS (AFTER WHICH T <sub>reset_act</sub> MUST PASS BEFORE RESET OUTPUT IS RELEASED)
FB below V <sub>reset_UV</sub> for longer than t <sub>reset_filt</sub>	FB above V <sub>reset_UV</sub> + V <sub>reset_hyst</sub> for longer than t <sub>reset_filt</sub>
FB above V <sub>reset_OV</sub> for longer than t <sub>reset_filt</sub>	FB below V <sub>reset_OV</sub> - V <sub>reset_hyst</sub> for longer than t <sub>reset_filt</sub>
Junction temperature exceeds T <sub>SD</sub>	Junction temperature falls below T <sub>SD</sub> – T <sub>SD_hyst</sub>
EN low	t <sub>EN</sub> passes after EN becomes high <sup>(1)</sup>
VIN falls below $V_{in\_UVLO}$ - $V_{in\_UVLO\_hyst}$ or VCC pin falls below $V_{cc\_UVLO}$ - $V_{cc\_UVLO\_hyst}$	Voltage on V <sub>IN</sub> exceeds V <sub>in_UVLO</sub> and VCC exceed V <sub>cc_UVLO</sub>

(1) As an additional safety feature, RESET remains low until approximately 1ms after soft start ends even if all other conditions in this table are met and t<sub>reset act</sub> has passed. Lockout during soft start does not require t<sub>reset act</sub> to pass before RESET is released.

The threshold voltage for the RESET function is specified taking advantage of the availability of the LM53600-Q1 internal feedback threshold to the RESET circuit. This allows a maximum threshold of 97% of selected output voltage to be specified at the same time as 95.7% of actual operating point. The net result is a more accurate reset function while expanding the system allowance for transient response without the need for extremely accurate internal circuitry. See output voltage error stack up comparison, below.

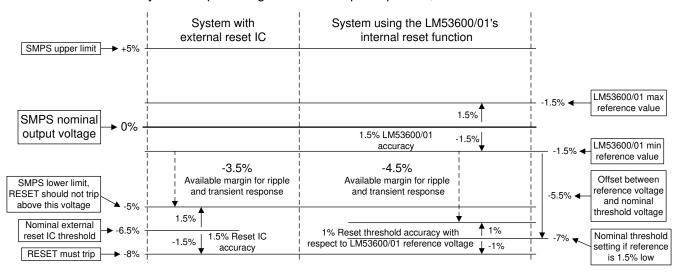


Figure 8-6. Reset Threshold Voltage Stack Up

#### 8.3.6 Forced PWM Operation

When constant frequency operation is more important than light load efficiency, the SYNC/MODE input of the LM53600-Q1 and LM53601-Q1 devices should be pulled high, or a valid synchronization input be provided. Once activated, this feature ensures that the switching frequency will stay above the AM frequency band, while operating between the minimum and maximum duty cycle limits. Essentially, the diode emulation feature is turned off in this mode. This means that the device will remain in CCM under light loads. Under conditions where the device must reduce the on-time or off-time below the ensured minimum to maintain regulation, the frequency will reduce to maintain the effective duty cycle required for regulation. This occurs for very high and very low input/output voltage ratios.

This feature may be activated and deactivated while the part is regulating without removing the load. This feature activates and deactivates gradually, over approximately 40  $\mu$ s, preventing perturbation of output voltage. When in FPWM mode, a limited reverse current is allowed through the inductor allowing power to pass from the regulators output to its input.

Note that while FPWM is activated, larger currents pass through the inductor, if lightly loaded, than in *auto* mode. This may result in more EMI, though at a predictable frequency. Once loads are heavy enough to necessitate CCM operation, FPWM mode has no measurable effect on regulator operation.

### 8.3.7 Auto Mode Operation and IQ VIN

If SYNC/MODE is held low for a period greater than a few microseconds, the LM53600-Q1 and LM53601-Q1 devices will enable automatic power saving light load operation and diode emulation. In this mode, if peak current needed to regulate output voltage drops below a selected value, the clock of the LM53600-Q1 or LM53601-Q1 device slows to maintain regulation. The gain of this clock slowing circuit is low to maintain stability. Output voltage with no load is approximately 1% higher than with a load high enough to allow full frequency operation.

 $I_{Q\_VIN}$  is the current consumed by a converter utilizing a LM53600-Q1 or LM53601-Q1 device while regulating without a load. While operating without a load, the LM53600-Q1 or LM53601-Q1 is only powering itself. The LM53600-Q1 and LM53601-Q1 device draws power from two sources, its VIN pin,  $I_Q$ , and either its FB pin for fixed versions or BIAS pin for adjustable versions,  $I_B$ . Since BIAS or FB is connected to the circuit's output, the power consumed is converted from input power with an effective efficiency,  $\eta_{eff}$ , of ~80%. Here, effective efficiency is the added input power needed when lightly loading the converter of the LM53600-Q1 and LM53601-Q1 devices is divided by the corresponding additional load. This allows unloaded current to be calculated as follows:

$$I_{Q_{VIN}} = I_{Q} + I_{EN} + (I_{B} + I_{div}) \frac{\text{Output Voltage}}{\eta_{eff} \times \text{Input Voltage}}$$
(1)

#### where

- I<sub>Q\_VIN</sub> is the current consumed by the Buck converter utilizing the LM53600-Q1 or LM53601-Q1 while unloaded
- I<sub>O</sub> is the current drawn by the LM53600-Q1 or LM53601-Q1 from its VIN terminal. See I<sub>O</sub> in section 7.6.
- I<sub>EN</sub> is current drawn by the LM53600-Q1 or LM53601-Q1 from its EN terminal. Include this current if EN is connected to VIN. See I<sub>EN</sub> in section 7.6. Note that this current drops to a very low value if connected to a voltage less than 5 V.
- I<sub>B</sub> is bias/feedback current drawn by the LM53600-Q1 or LM53601-Q1 while the Buck converter utilizing it is unloaded. See I<sub>B</sub> in section 7.6.
- I<sub>div</sub> is the current drawn by the feedback voltage divider used to set output voltage for adjustable devices.
   This current is zero for fixed output voltage devices.
- n<sub>eff</sub> is the light load efficiency of the Buck converter with I<sub>Q\_VIN</sub> removed from the Buck converter's input current. 0.8 is a conservative value that can be used under normal operating conditions

Note that the EN pin consumes a few microamperes when tied to high; see  $I_{EN}$ . Add  $I_{EN}$  to  $I_{Q}$  as shown in the above equation if EN is tied to  $V_{IN}$ . If EN is tied to a voltage less than 5 V, virtually no current is consumed allowing EN to be used as a UVL once a voltage divider is added.

### 8.3.8 SYNC Operation

Often it is desirable to synchronize the operation of multiple regulators in a single system. This technique results in better defined EMI and can reduce the need for capacitance on some power rails. The LM53600-Q1 and LM53601-Q1 devices provide a SYNC/MODE input, which allows synchronization with an external clock. The LM53600-Q1/LM53601-Q1 implements an in-phase locking scheme – the rising edge of the clock signal provided to the input of the LM53600-Q1 or LM53601-Q1 device corresponds to turning on the high side device within the LM53600-Q1 or LM53601-Q1. This function is implemented using phase locking over a limited frequency range eliminating large glitches upon initial application of an external clock. The clock fed into the LM53600-Q1 or LM53601-Q1 device replaces the internal free running clock but does not affect frequency fold-back operation. Output voltage will continue to be well regulated with duty factors outside of the normal 15% through 77% range though at reduced frequency.

The device remains in FPWM mode and operates in CCM for light loads when synchronization input is provided.



## 8.3.9 Spread Spectrum

The spread spectrum is a factory option. In order to find which parts have spread spectrum enabled, see *Section* 5.

The purpose of the spread spectrum is to eliminate peak emissions at specific frequencies by spreading emissions across a wider range of frequencies than a part with fixed frequency operation. In most systems containing the LM53600-Q1 and LM53601-Q1 devices, low frequency conducted emissions from the first few harmonics of the switching frequency can be easily filtered. A more difficult design criterion is reduction of emissions at higher harmonics which fall in the FM band. These harmonics often couple to the environment through electric fields around the switch node. The LM53600-Q1 and LM53601-Q1 devices use a ±4% spread of frequencies which spread energy smoothly across the FM band but is small enough to limit sub-harmonic emissions below its switching frequency. Peak emissions at the part's switching frequency are only reduced by slightly less than 1 dB, while peaks in the FM band are typically reduced by more than 6dB.

The LM53600-Q1 and LM53601-Q1 devices use a cycle to cycle frequency hopping method based on a linear feedback shift register (LFSR). Intelligent pseudo random generator limits cycle to cycle frequency changes to limit output ripple. Pseudo random pattern repeats by approximately 7 Hz which is below the audio band.

The spread spectrum is only available while the clock of the LM53600-Q1 and LM53601-Q1 devices is free running at its natural frequency. Any of the following conditions overrides spread spectrum, turning it off:

- 1. An external clock is applied to the SYNC/MODE terminal.
- 2. The clock is slowed due to operation low input voltage this is operation in dropout.
- 3. The clock is slowed due to high input voltage input voltage above approximately 21 V disables spread spectrum.
- 4. The clock is slowed under light load in Auto mode this is normally not seen above 200 mA of load. In FPWM mode, spread spectrum is active even if there is no load.

#### **8.4 Device Functional Modes**

### 8.4.1 Shutdown

The LM53600-Q1 and LM53601-Q1 devices shut down most internal circuitry and both high side and low side power switches connected to its switch node under any of the following conditions:

- 1. EN is below V<sub>FN</sub>
- 2. VIN is below V<sub>in UVLO</sub>
- 3. Junction temperature exceeds T<sub>SD</sub>

Note that the above conditions have hysteresis. Also,  $\overline{\text{RESET}}$  remains active to a very low input voltage,  $V_{\text{reset\_valid}}$ .

### 8.4.2 FPWM Operation

If SYNC/MODE is above  $V_{SYNC/MODE}$  high or a valid synchronizing is applied to SYNC/MODE, constant frequency operation is maintained across load. This requires negative current be allowed in the inductor if load is light. If a large negative load is present, operation is halted by a reverse current limit,  $I_{I-NEG}$ .

## 8.4.3 Auto Mode Operation

If SYNC/MODE is below  $V_{SYNC/MODE}$  low, reverse current in the inductor is not allowed – this feature is called diode emulation. While load is heavy, operation is the same as in FPWM operation. If load is light, switching frequency is reduced saving energy and allowing regulation to be maintained. Note that while under loads which require moderate reduction of frequency, pulses often are seen if small groups, often called burst mode operation, which can increase output ripple. Under this condition, output ripple can be reduced by increasing output capacitance.



## 9 Applications and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 9.1 Application Information

The LM53600-Q1 and LM53601-Q1 are step-down DC–DC converters, typically used to convert a higher DC voltage to a lower DC voltage with a maximum output current of either 1 A or 650 mA. The following design procedure can be used to select components for the LM53600-Q1 or LM53601-Q1. Alternately, the WEBENCH® Design Tool may be used to generate a complete design. This tool utilizes an iterative design procedure and has access to a comprehensive database of components. This allows the tool to create an optimized design and allows the user to experiment with various design options.

Figure 9-1 shows the minimum required application circuit for the fixed output voltage versions, while Figure 9-2 shows the connections for complete processor control of the LM53601-Q1. Please refer to these figures while following the design procedures. Table 9-2 provides an example of typical design requirements.

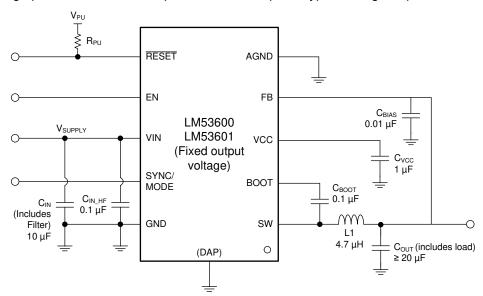


Figure 9-1. Off Battery, Automotive, Fixed Output Voltage, Buck, 2.1 MHz, Spread Spectrum



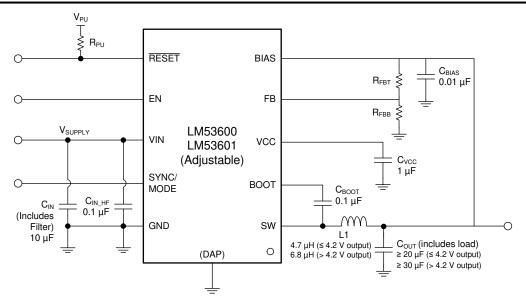


Figure 9-2. Off Battery, Automotive, Adjustable Output Voltage, Buck, 2.1 MHz, Spread Spectrum

## 9.2 Typical Applications

## 9.2.1 Off-Battery 5-V, 1-A Output Automotive Converter with Spread Spectrum

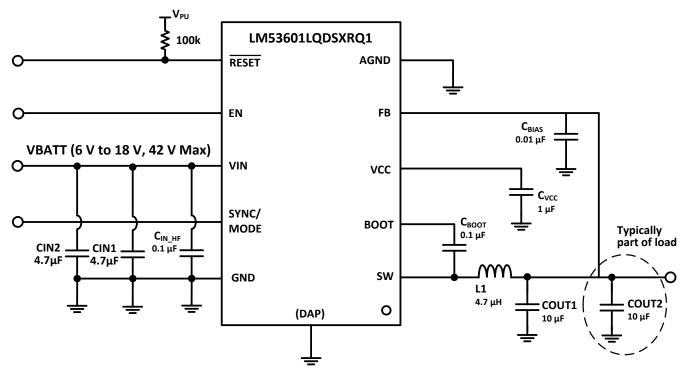


Figure 9-3. Typical LM53601LQDSXRQ1 Application Schematic



### 9.2.1.1 Design Requirements

For this design example, use the parameters listed in Table 9-1 as the input parameters.

**Table 9-1. Design Parameters** 

DESIGN PARAMETER	VALUE	COMMENT
Input voltage range	6 V to 18 V with excursions to 42 V	This converter will run continuously up to 36 V
Output voltage	5 V	Fixed option used
Output current range	No Load to 1 A	
Light load mode	Switchable	
Spread spectrum	Enabled	Factory option

### 9.2.1.2 Detailed Design Procedure

#### 9.2.1.2.1 Inductor Selection

The LM53600-Q1 and LM53601-Q1 devices run in current mode and has internal compensation. This compensation is stable with inductance between 4  $\mu$ H and 10  $\mu$ H. For most applications, 4.7  $\mu$ H should be used with fixed 5-V and 3.3-V versions of the LM53600-Q1 and LM53601-Q1 devices. The output inductor is limited by current ripple while operating at high input voltage to a minimum rating of 4.7  $\mu$ H for 3.3 V and 5-V fixed output devices. Since adjustable devices operate at the same frequency under high input voltage conditions as devices set to deliver 3.3 V, inductor current ripple at high input voltages can become excessive while using a 4.7 $\mu$ H while using an adjustable device that is delivering output voltage above 4.2 V. 6.8  $\mu$ H is recommended if an adjustable device is used to produce output voltage above 4.2 V. Not exceeding 6.8  $\mu$ H is recommended since use of large inductance causes poor transient load response. For the LM53601-Q1 (1-A output), a saturation rating of about 2 A is recommended since this is the maximum current limit rating. Likewise, a saturation current rating of about 1.5 A is recommended for the LM53600-Q1. See I<sub>L</sub> HS in the data sheet.

**Table 9-2. Output Inductor** 

Table 9-2. Output inductor					
PART TYPE	RECOMMENDED INDUCTANCE RATING(1)	RECOMMENDED MINIMUM SATURATION CURRENT <sup>(2)</sup>	COMMENT		
LM53601-Q1 3.3 V and 5 V	4.7 μH	about 2 A	6.8 µH works in systems with less demanding transient load requirements		
LM53601-Q1 ADJ set to ≤ 4.2-V output	4.7 μH	about 2 A			
LM53601-Q1 ADJ set to > 4.2-V output	6.8 µH	about 2 A			
LM53600-Q1 3.3 V and 5 V	4.7 μH	about 1.5 A			
LM53600-Q1 ADJ set to ≤ 4.2-V output	4.7 μH	about 1.5 A	Up to 10 μH works in systems with less demanding transient load requirements		
LM53600-Q1 ADJ set to > 4.2-V output	6.8 µH	about 1.5 A			

<sup>(1)</sup> The values shown in this table are standard inductance ratings. The LM53600-Q1/LM53601-Q1 tolerates reduced inductance due to DC current and temperature.

### 9.2.1.2.2 Output Capacitor Selection

The current mode control scheme of the LM53600-Q1 and LM53601-Q1 devices allows operation over a wide range of output capacitance. A minimum of 10  $\mu$ F is needed to ensure stability. Capacitance above 20  $\mu$ F is recommended to ensure load transient response typically desired in systems. 40  $\mu$ F is recommended for applications with demanding load transient requirements and for which Auto mode ripple is important. 40  $\mu$ F also aids devices with output voltage below 4-V transition into high voltage mode. Capacitance above 400  $\mu$ F can cause excessive current to be drawn during start up so is not recommended. These capacitance values include load capacitance – only 10  $\mu$ F is needed near to the LM53600-Q1 and LM53601-Q1 devices. Output capacitors

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<sup>(2)</sup> The LM53600-Q1/LM53601-Q1 tolerates partial saturation of inductors (reduction of ~40% reduction of inductance of the current value listed due to saturation. Partial saturation may reduce maximum current available at maximum voltage).

should have low ESR to reduce output ripple. These capacitors should have at least X7R rating and should be of automotive grade if used in automotive applications.

Table 9-3. Output Capacitor

Table of Cathat Cahacite.			
LM53600-Q1 AND LM53601-Q1 TYPE AND SYSTEM NEED	RECOMMENDED MINIMUM TOTAL OUTPUT CAPACITANCE	COMMENTS	
LM53600-Q1 5 V	20 μF	Approximately 200-mV/A step load response with 1-µs rise/fall time.	
LM53601-Q1 5 V with typical system requirements	20 μF	Approximately 200-mV/A step load response with 1-µs rise/fall time.	
LM53601-Q1 5V in high performance systems	40 μF	Approximately 150-mV/A step load, approximately 20-mV maximum Auto mode ripple	
LM53600-Q1/LM53601-Q1 3.3 V and adjustable parts with less than 4.2-V output setting with typical system requirements	20 μF	Approximately 200-mV/A step load response with 1µs rise/fall time, up to 60 mV of ripple during transition into high voltage mode and in Auto mode.	
LM53600-Q1/LM53601-Q1 3.3 V and adjustable parts with less than 4.2 V in high performance systems	40 μF	Approximately 150-mV/A step load, approximately 30-mV maximum Auto mode ripple, and 15-mV maximum HV mode transition ripple.	
LM53600-Q1 ADJ set to greater than 4.2-V output	40 μF	Larger capacitance is necessitated by higher inductance needed.	

### 9.2.1.2.3 Input Capacitor Selection

Input capacitors serve two important functions: The first is to reduce input voltage ripple into the LM53601-Q1 and the input filter of the system. The second is to reduce high frequency noise. These two functions are implemented most effectively with separate capacitors, see Table 9-4.

**Table 9-4. Input Capacitor** 

CAPACITOR	RECOMMENDED VALUE	COMMENT
C <sub>IN_HF</sub>	0.1 μF	This capacitor is used to suppress high frequency noise originating during switching events. It is important to place capacitor as close to the LM53600-Q1 and LM53601-Q1 devices as design rules allow. Position is more important than exact capacity. Once high frequency propagates into a system, it can be hard to suppress or filter. Since this capacitor will be exposed to battery voltage in systems that operate directly off of battery, 50 V or greater rating is recommended.
C <sub>IN</sub>	10 μF	This capacitance is used to suppress input ripple and transients due to output load transients. If CIN is too small, input voltage may dip during load transients resetting the system if the system is operated under low voltage conditions. 10 $\mu$ F is intended to include all capacitance in the LM53600-Q1/LM53601-Q1's input node. 4.7 $\mu$ F adjacent to the LM53600-Q1 and LM53601-Q1 devices is recommended. Since this capacitor will be exposed to battery voltage in systems that operate directly off of battery, 50 V or greater rating is recommended.

Table 9-5 shows recommended capacitor values other than input and output capacitors.

### **Table 9-5. Other Capacitors**

CAPACITOR	MINIMUM VALUE	COMMENT
C <sub>BOOT</sub>	0.1 μF	While a voltage rating of only 5 V is necessary, using a higher voltage rating is recommended.
C <sub>VCC</sub>	1 μF	While a voltage rating of only 5 V is necessary, 16-V capacitors have a low voltage coefficient.
C <sub>BIAS</sub>	0.01 µF	This capacitor should be rated to survive output voltage.

Note that performance of converters utilizing an adjustable version of the LM53600-Q1 and LM53601-Q1 devices may be enhanced by adding  $C_{FF}$ , a capacitor in parallel with  $R_{FBT}$ . 100 pF is recommended.

#### 9.2.1.2.4 FB Voltage Divider for Adjustable Versions

The adjustable version of the LM53600RB-Q1 and LM53601RB-Q1 devices regulates output voltage to a level that results in the FB node being  $V_{ref}$  which is approximately 1.0 V; see Section 7.5 Output voltage given a specific feedback divider can be calculated using the following equation:

Output Voltage = 
$$V_{ref} \times \frac{R_{FBB} + R_{FBT}}{R_{FBB}}$$
 (2)

See typical applications schematic for adjustable versions of the LM53600-Q1 and LM53601-Q1 devices. Since the value of  $R_{FBT}$  is typically set by board leakage considerations, the above equation can be solved for  $R_{FBB}$ , the remaining unknown:

$$R_{FBB} = \frac{V_{ref} \times R_{FBT}}{Output \ Voltage - V_{ref}}$$
(3)

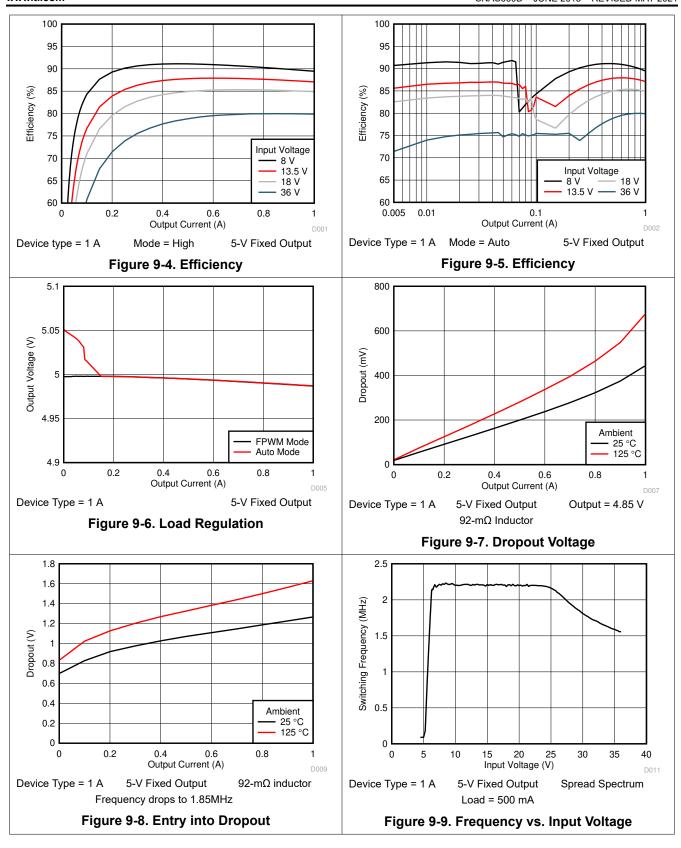
Note that typically, 100 k $\Omega$  is used for R<sub>FBT</sub>.

#### 9.2.1.2.5 RPII - RESET Pull Up Resistor

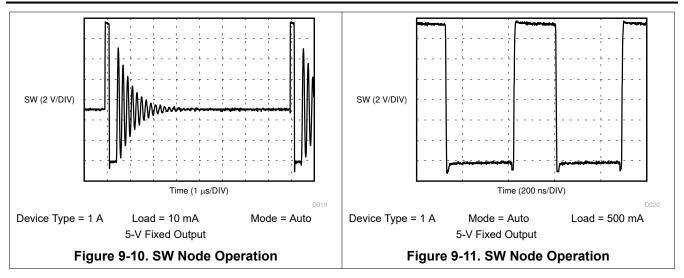
While RESET is rated to sink up to 8 mA, under low, 1.5-V input voltage conditions, a low output level is only ensured with loads of 50  $\mu$ A. If accurate RESET output is needed with 1.5-V input voltage, 100 k $\Omega$  should be used to pull up to 5 V, or a 66-k $\Omega$  resistor should be used when pulling up to a 3.3-V supply. If input voltage is above 3.8 V, values as low as 10 k $\Omega$  or 6.6 k $\Omega$  can be used to pull up to 5 V or 3.3 V, respectively. Other considerations, such as power consumption may increase any of the values listed above.

### 9.2.1.3 Application Curves

The following characteristics apply only to the circuit shown in Figure 9-3. These parameters are not tested and represent typical performance only. Unless otherwise stated, the following conditions apply:  $V_{IN} = 13.5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .







## 9.2.2 Off-Battery 3.3 V, 1 A Output Automotive Converter with Spread Spectrum

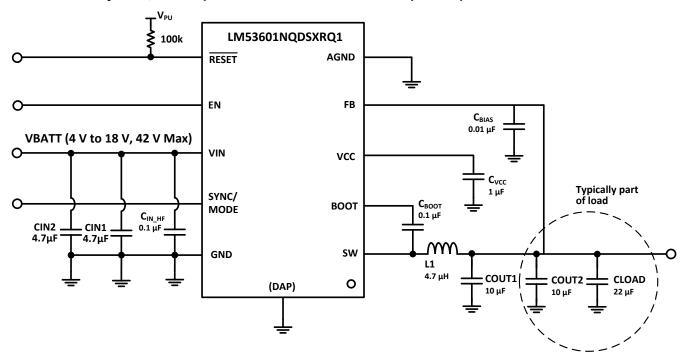


Figure 9-12. Typical LM53601NQDSXRQ1 Application Schematic

### 9.2.2.1 Design Requirements

For this design example, use the parameters in Table 9-6 as the input parameters.

**Table 9-6. Design Parameters** 

DESIGN PARAMETER	VALUE	COMMENT
Input voltage range	4 V to 18 V with excursions to 42 V	This converter will run continuously up to 36 V
Output voltage	3.3 V	Fixed option used
Output current range	No load to 1 A	
Light load mode	Switchable	
Spread spectrum	Enabled	Factory option



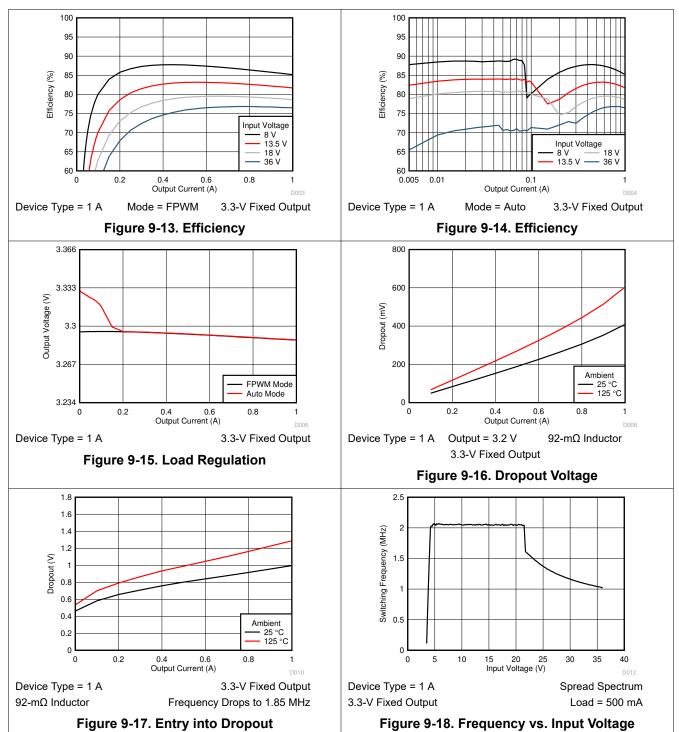
## 9.2.2.2 Design Procedure

The same detailed design procedure as shown starting in section 7.1.2.1 is used to create the schematic for this example. The most important difference is that the LM53601NQDSXRQ1 is used in place of the LM53601LQDSXRQ1. In addition, more output capacitance is recommended for this option. Most output capacitance will be part of the load and be used as input bypassing for the load.



### 9.2.2.3 Application Curves

The following characteristics apply only to the circuit shown in Figure 9-12. These parameters are not tested and represent typical performance only. Unless otherwise stated, the following conditions apply:  $V_{IN} = 13.5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .



### 9.3 Do's and Don't's

- Don't: Exceed the Section 7.1.
- Don't: Exceed the Section 7.2.



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- Don't: Exceed the Section 7.3.
- Don't: Allow the EN, FPWM or SYNC input to float.
- Don't: Allow the output voltage to exceed the input voltage, nor go below ground.
- Don't: Use the thermal data given in the Thermal Information table to design your application.
- Do: Follow all of the guidelines and/or suggestions found in this data sheet, before committing your design to
  production. TI Application Engineers are ready to help critique your design and PCB layout to help make your
  project a success.
- Do: Refer to the helpful documents found in Table 11-1 and Table 11-2.

## 10 Power Supply Recommendations

The LM53600-Q1 and LM53601-Q1 devices are designed for automotive direct off battery applications needing minimal protection. Protection recommended includes reverse battery protection and EMI/ESD filtering. The LM53600-Q1 and LM53601-Q1 devices are able to continue regulating during load dump with peak voltage less than 42 V, double battery (jump start) conditions down to input voltage as low as  $V_{DROP}$  above the selected output voltage. In addition, the LM53600-Q1 and LM53601-Q1 devices continue to operate though may be out of regulation with input voltage as low as 3.8 V. This allows the LM53600-Q1 and LM53601-Q1 devices to operate through cranking in all but the most demanding systems.

If the regulator is connected to the input supply through long wires or PCB traces, special care is required to achieve good performance. The parasitic inductance and resistance of the input cables can have an adverse effect on the operation of the regulator. The parasitic inductance, in combination with the low ESR ceramic input capacitors, can form an under-damped resonant circuit. This circuit may cause over-voltage transients at the VIN pin, each time the input supply is cycled on and off. The parasitic resistance will cause the voltage at the VIN pin to dip when the load on the regulator is switched on, or exhibits a transient. If the regulator is operating close to the minimum input voltage, this dip may cause the device to shutdown and/or reset. The best way to solve these kinds of issues is to reduce the distance from the input supply to the regulator and/or use an aluminum or tantalum input capacitor in parallel with the ceramics. The moderate ESR of these types of capacitors will help to damp the input resonant circuit and reduce any voltage overshoots. A value in the range of 20  $\mu$ F to 100  $\mu$ F is usually sufficient to provide input damping and help to hold the input voltage steady during large load transients.

Sometimes, for other system considerations, an input filter is used in front of the regulator. This can lead to instability, as well as some of the effects mentioned above, unless it is designed carefully. The *Simple Success with Conducted EMI for DC–DC Converters* User's Guide (SNVA489) provides helpful suggestions when designing an input filter for any switching regulator

In some cases, a Transient Voltage Suppressor (TVS) is used on the input of regulators. One class of this device has a *snap-back* V-I characteristic (thyristor type). The use of a device with this type of characteristic is not recommend. When the TVS *fires*, the clamping voltage drops to a very low value. If this holding voltage is less than the output voltage of the regulator, the output capacitors will be discharged through the regulator back to the input. This uncontrolled current flow could damage the regulator.



## 11 Layout

## 11.1 Layout Guidelines

The following list is in order of importance starting with the most important item:-

- Place high frequency input bypass capacitor, Cinhf, as close to the LM53600-Q1 and LM53601-Q1 devices as possible.
- Connect AGND and GND to the DAP immediately adjacent to the LM53600-Q1 and LM53601-Q1 devices.
- Do not interrupt the ground plain under the loop containing the VIN and GND pins and Cinhf of the LM53600-Q1 and LM53601-Q1 devices.
- The boot capacitor, CBOOT, should be close to the LM53601-Q1 and the loop from the SW pin, through the boot capacitor and into the BOOT pin should be kept as small as possible.
- Keep the SW node as small as possible. It should be wide enough to carry the converter's full current without significant drop.
- 4.7 µF of bypassing should be close to the input of the LM53600-Q1 and LM53601-Q1 devices.
- Place CVCC, the VCC pin's bypass, and CBIAS, the bypass for FB for fixed voltage devices and BIAS for adjustable devices as close to the LM53600-Q1 and LM53601-Q1 devices as possible.
- The first output the trace from the output inductor to the output node should run by an output capacitor before joining the rest of the output node.
- Keep 10 µF close to the output (output inductor and GND) of the LM53600-Q1 and LM53601-Q1 devices.
- · Clear the layer beneath the SW node.

Table 11-1. PCB Layout Resources

TITLE	LINK
AN-1149 Layout Guidelines for Switching Power Supplies	SNVA021
AN-1229 Simple Switcher PCB Layout Guidelines	SNVA054
Constructing Your Power Supply- Layout Considerations	SLUP230
SNVA721 Low Radiated EMI Layout Made SIMPLE with LM4360x and LM4600x	SNVA721

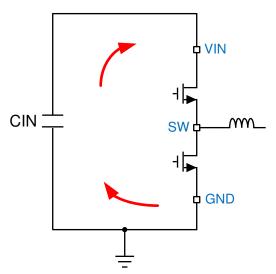


Figure 11-1. Current Loops with Fast Transients

### 11.1.1 Ground and Thermal Plane Considerations

As mentioned above, it is recommended to use one of the middle layers as a solid ground plane. A ground plane provides shielding for sensitive circuits and traces. It also provides a quiet reference potential for the control circuitry. The AGND and PGND pins should be connected to the ground plane using vias right next to the bypass capacitors. PGND pins are connected to the source of the internal low side MOSFET switch. They should be connected directly to the grounds of the input and output capacitors. The PGND net contains noise



at the switching frequency and may bounce due to load variations. The PGND trace, as well as PVIN and SW traces, should be constrained to one side of the ground plane. The other side of the ground plane contains much less noise and should be used for sensitive routes.

It is recommended to provide adequate device heat sinking by utilizing the exposed pad (EP) of the IC as the primary thermal path. Use a minimum 4 by 4 array of 10 mil thermal vias to connect the EP to the system ground plane for heat sinking. The vias should be evenly distributed under the exposed pad. Use as much copper as possible for system ground plane on the top and bottom layers for the best heat dissipation. It is recommended to use a four-layer board with the copper thickness, starting from the top, as: 2 oz / 1 oz / 2 oz. A four-layer board with enough copper thickness and proper layout provides low current conduction impedance, proper shielding and lower thermal resistance.

Table 11-2. Resources for Thermal PCB Design

TITLE	LINK
AN-2020 Thermal Design By Insight, Not Hindsight	SNVA419
AN-1520 A Guide to Board Layout for Best Thermal Resistance for Exposed Pad Packages	SNVA183
SPRA953B Semiconductor and IC Package Thermal Metrics	SPRA953
SNVA719 Thermal Design made Simple with LM43603 and LM43602	SNVA719
SLMA002 PowerPAD™ Thermally Enhanced Package	SLMA002
SLMA004 PowerPAD Made Easy	SLMA004
SBVA025 Using New Thermal Metrics	SBVA025



### 11.2 Layout Example

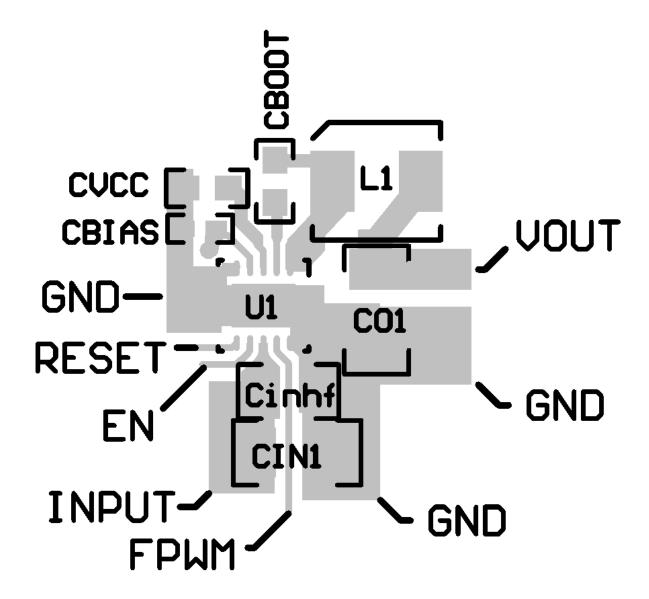


Figure 11-2. Fixed Output Version

Figure 11-2 shows an example layout for a fixed output version of the LM53600-Q1 and LM53601-Q1 similar to the one used in the Rev A EVM. Note that the via next to CBIAS connects on the back side of the board to VOUT near CO1. This layout shows 10  $\mu$ F of output capacitance and 4.7  $\mu$ F of input capacitance. An additional >10  $\mu$ F of output capacitance and about 4.7  $\mu$ F of input capacitance is assumed to be elsewhere in the system. A solid, unbroken ground plane is under this entire circuit except immediately below the SW node.

## 12 Device and Documentation Support

## 12.1 Documentation Support

### 12.1.1 Related Documentation

For related documentation request the following:

AN-1149 Layout Guidelines for Switching Power Supplies (SNVA021)

Low Radiated EMI Layout Made SIMPLE with LM4360x and LM4600x (SNVA721)

Constructing Your Power Supply – Layout Considerations (SLUP230)

AN-1229 Simple Switcher PCB Layout Guidelines (SNVA054)

Using New Thermal Metrics (SBVA025)

PowerPAD Made Easy (SLMA004)

PowerPAD™ Thermally Enhanced Package (SLMA002)

Thermal Design made Simple with LM43603 and LM43602 (SNVA719)

Semiconductor and IC Package Thermal Metrics (SPRA953)

AN-2020 Thermal Design By Insight, Not Hindsight (SNVA419)

AN-1520 A Guide to Board Layout for Best Thermal Resistance for Exposed Pad Packages (SNVA183)

Simple Success with Conducted EMI for DC-DC Converters User's Guide (SNVA489)

EVM User's Guide for Adjustable Versions of the LM53600-Q1 and LM53601-Q1 (SNAU190)

EVM User's Guide for Fixed Versions of the LM53600-Q1 and LM53601-Q1 (SNAU191)

## 12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 12.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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### 12.4 Trademarks

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### 12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 12.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.



## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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## **PACKAGING INFORMATION**

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
LM536003QDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	53603
LM536003QDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	53603
LM536003QDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	53603
LM536003QDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	53603
LM536005QDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	53605
LM536005QDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	53605
LM536005QDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	53605
LM536005QDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	53605
LM53600AQDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5360A
LM53600AQDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5360A
LM53600AQDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5360A
LM53600AQDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5360A
LM53600LQDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5360L
LM53600LQDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5360L
LM53600LQDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5360L
LM53600LQDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5360L
LM53600MQDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5360M
LM53600MQDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5360M
LM53600MQDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5360M
LM53600MQDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5360M
LM53600MQUDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 150	360MU
LM53600MQUDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 150	360MU
LM53600NQDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5360N
LM53600NQDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5360N
LM53600NQDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5360N
LM53600NQDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5360N
LM536013QDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	53613
LM536013QDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	53613
LM536013QDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	53613





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Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
LM536013QDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	53613
LM536013QUDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 150	3613U
LM536013QUDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 150	3613U
LM536015QDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	53615
LM536015QDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	53615
LM536015QDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	53615
LM536015QDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	53615
LM536015QUDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 150	3615U
LM536015QUDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 150	3615U
LM53601AQDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5361A
LM53601AQDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5361A
LM53601AQDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5361A
LM53601AQDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5361A
LM53601LQDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5361L
LM53601LQDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5361L
LM53601LQDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5361L
LM53601LQDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5361L
LM53601MQDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5361M
LM53601MQDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5361M
LM53601MQDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5361M
LM53601MQDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5361M
LM53601MQUDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 150	361MU
LM53601MQUDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 150	361MU
LM53601NQDSXRQ1	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5361N
LM53601NQDSXRQ1.A	Active	Production	WSON (DSX)   10	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5361N
LM53601NQDSXTQ1	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 150	5361N
LM53601NQDSXTQ1.A	Active	Production	WSON (DSX)   10	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	5361N

<sup>(1)</sup> Status: For more details on status, see our product life cycle.



## PACKAGE OPTION ADDENDUM

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- (2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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### TAPE AND REEL INFORMATION





Γ	A0	Dimension designed to accommodate the component width
	В0	Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
	P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM536003QDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM536003QDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM536005QDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM536005QDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53600AQDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53600AQDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53600LQDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53600LQDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53600MQDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53600MQDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53600MQUDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
LM53600NQDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53600NQDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM536013QDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM536013QDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM536013QUDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2



## **PACKAGE MATERIALS INFORMATION**

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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM536015QDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM536015QDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM536015QUDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
LM53601AQDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53601AQDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53601LQDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53601LQDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53601MQDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53601MQDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53601MQUDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
LM53601NQDSXRQ1	WSON	DSX	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM53601NQDSXTQ1	WSON	DSX	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2



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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM536003QDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM536003QDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0
LM536005QDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM536005QDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0
LM53600AQDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM53600AQDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0
LM53600LQDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM53600LQDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0
LM53600MQDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM53600MQDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0
LM53600MQUDSXRQ1	WSON	DSX	10	3000	367.0	367.0	38.0
LM53600NQDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM53600NQDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0
LM536013QDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM536013QDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0
LM536013QUDSXRQ1	WSON	DSX	10	3000	367.0	367.0	38.0
LM536015QDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM536015QDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0



# **PACKAGE MATERIALS INFORMATION**

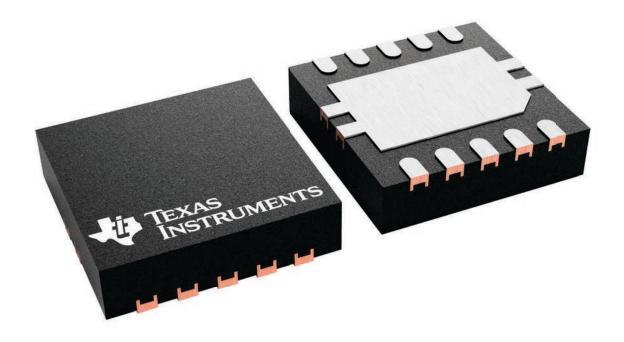
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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM536015QUDSXRQ1	WSON	DSX	10	3000	367.0	367.0	38.0
LM53601AQDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM53601AQDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0
LM53601LQDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM53601LQDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0
LM53601MQDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM53601MQDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0
LM53601MQUDSXRQ1	WSON	DSX	10	3000	367.0	367.0	38.0
LM53601NQDSXRQ1	WSON	DSX	10	3000	367.0	367.0	35.0
LM53601NQDSXTQ1	WSON	DSX	10	250	210.0	185.0	35.0

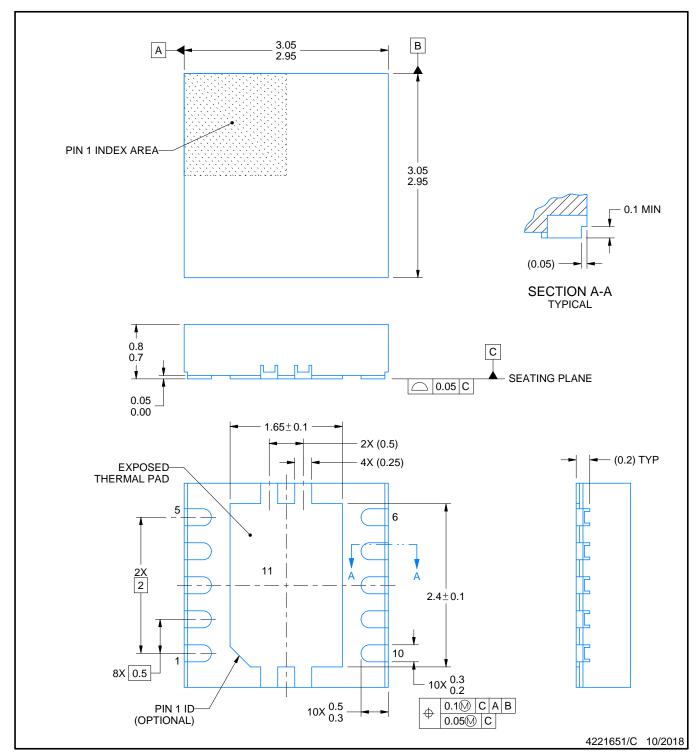
3 x 3, 0.5 mm pitch

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



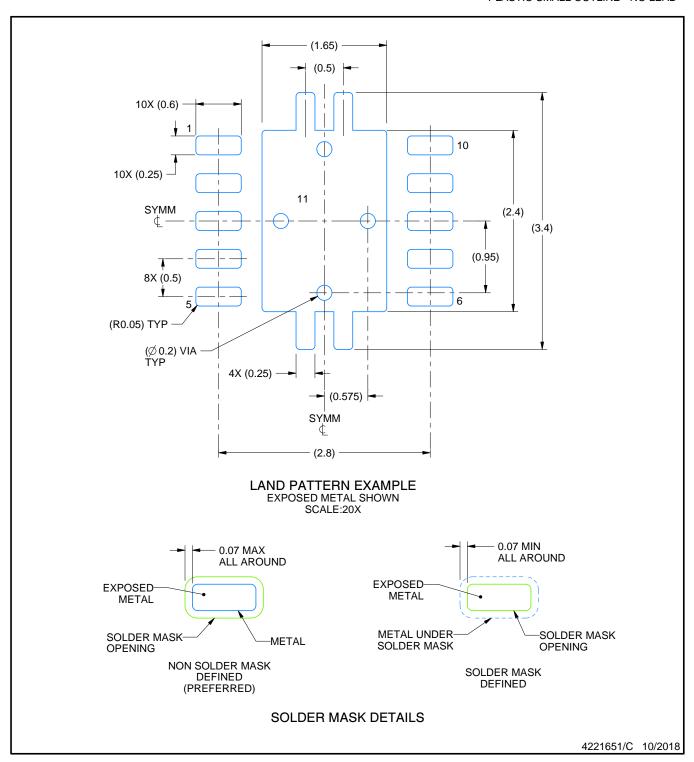




### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

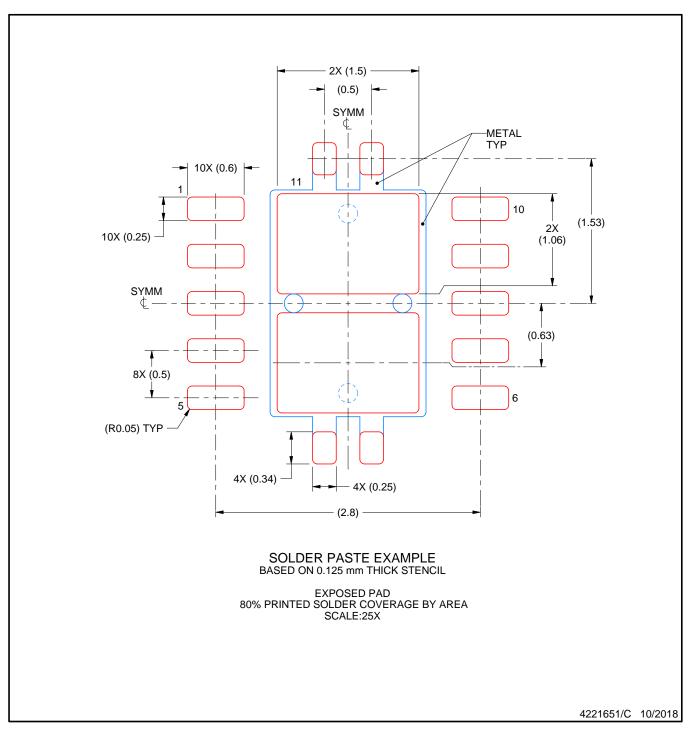




NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



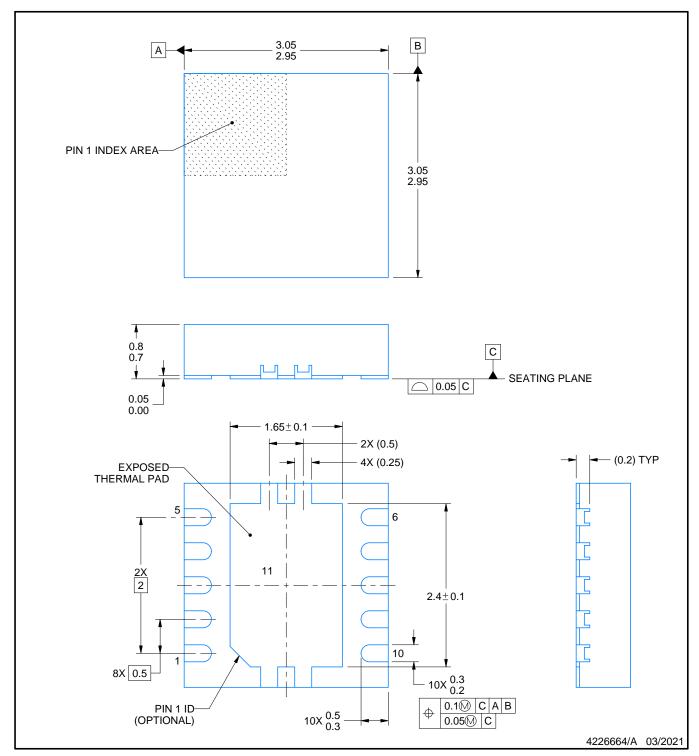


NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



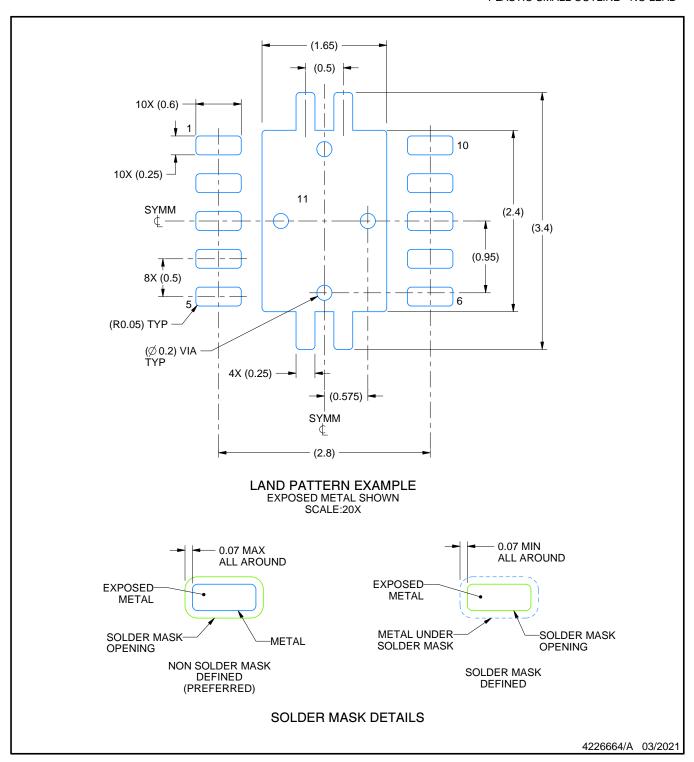




### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
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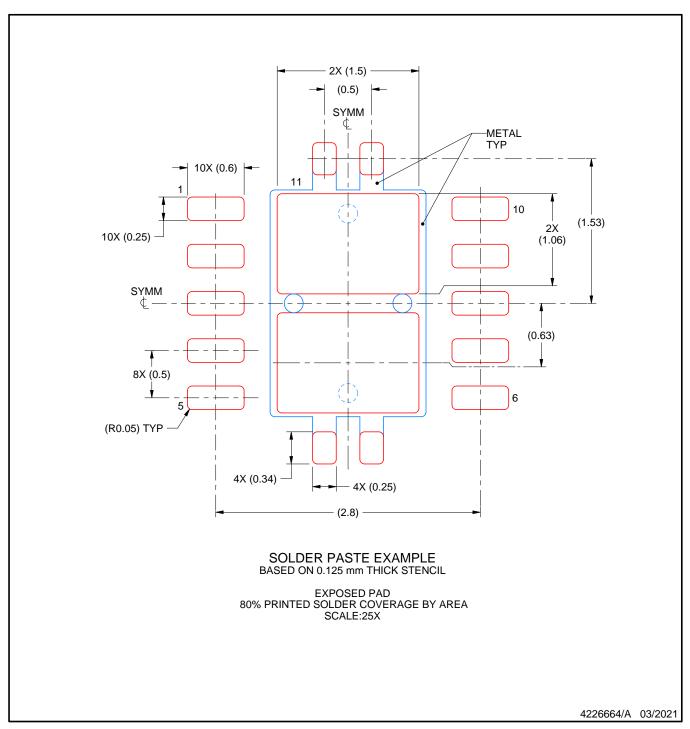




NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



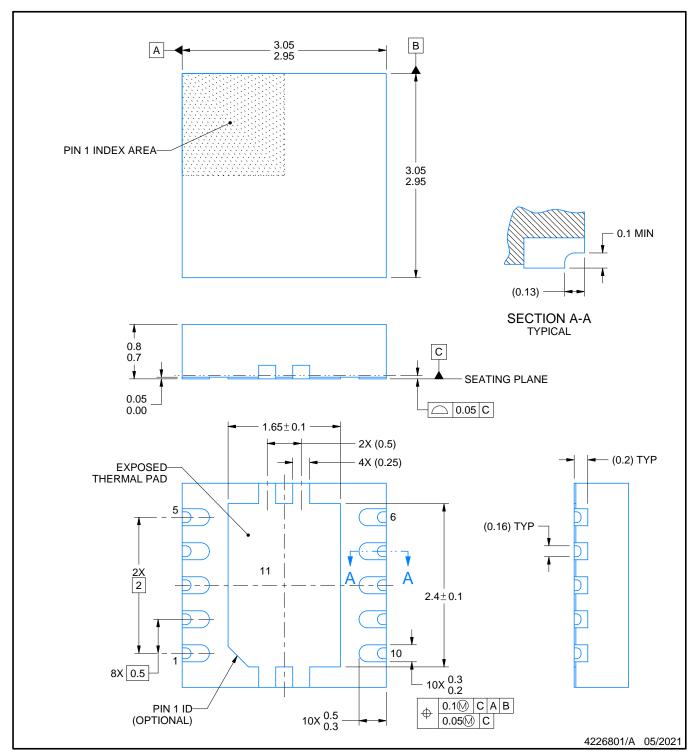


NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



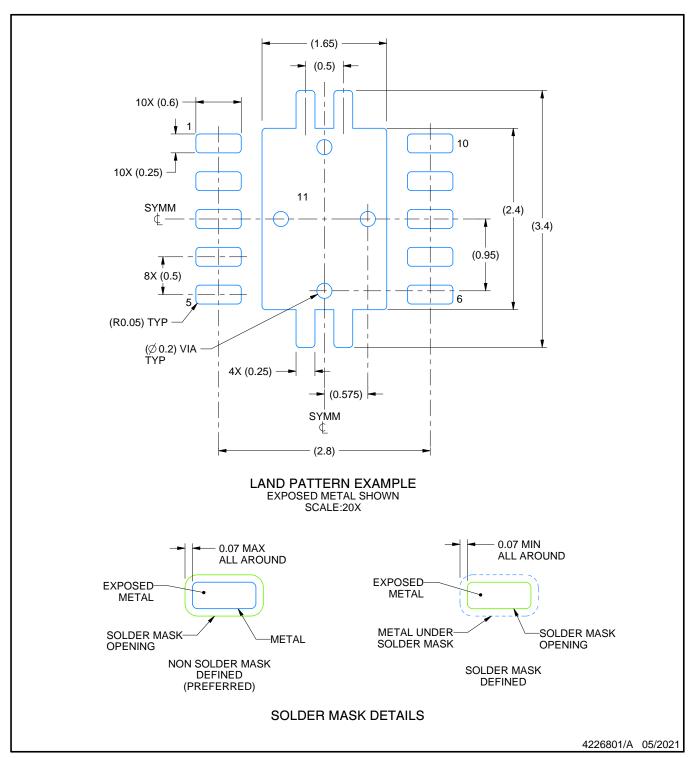




### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

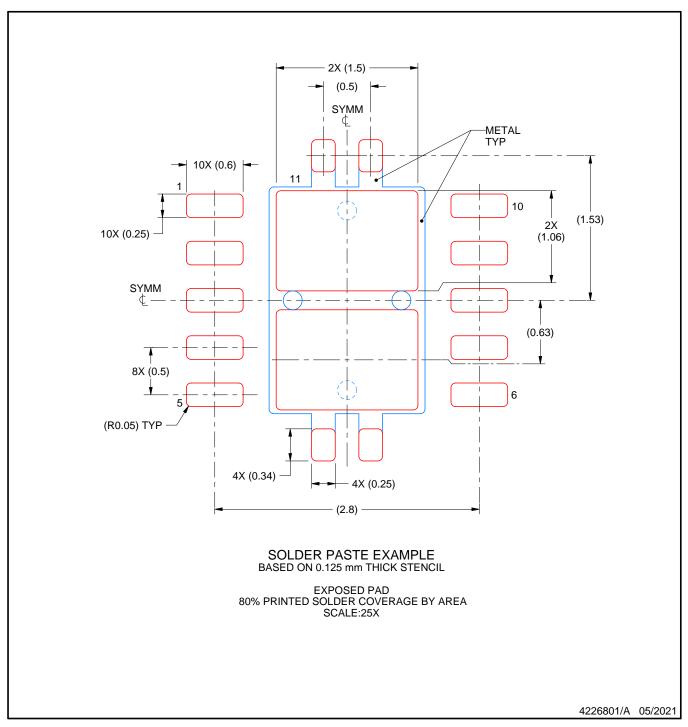




NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.





NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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